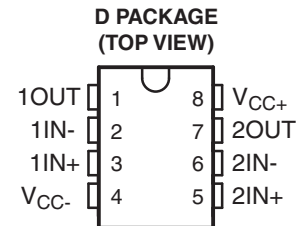


Excilibur™ LOW-NOISE HIGH-SPEED PRECISION OPERATIONAL AMPLIFIER

FEATURES

- **Qualified for Automotive Applications**
- **Low Noise**
 - 10 Hz: 15 nV/ $\sqrt{\text{Hz}}$
 - 1 kHz: 10.5 nV/ $\sqrt{\text{Hz}}$
- **10000-pF Load Capability**
- **20-mA Short-Circuit Output Current (Min)**
- **27-V/ μs Slew Rate (Min)**
- **High Gain-Bandwidth Product: 5.9 MHz**
- **Single or Split Supply: 4 V to 44 V**
- **Fast Settling Time**
 - 340 ns to 0.1%
 - 400 ns to 0.01%
- **Large Output Swing:**
 $V_{CC-} + 0.1 \text{ V}$ to $V_{CC+} - 1 \text{ V}$



DESCRIPTION/ORDERING INFORMATION

The TLE2142 device is a high-performance, internally compensated operational amplifier built using the Texas Instruments complementary bipolar Excilibur™ process. It is a pin-compatible upgrade to standard industry products.

The design incorporates an input stage that simultaneously achieves low audio-band noise of 10.5 nV/ $\sqrt{\text{Hz}}$ with a 10-Hz 1/f corner and symmetrical 40-V/ μs slew rate typically with loads up to 800 pF. The resulting low distortion and high power bandwidth are important in high-fidelity audio applications. A fast settling time of 340 ns to 0.1% of a 10-V step with a 2-k Ω /100-pF load is useful in fast actuator/positioning drivers. Under similar test conditions, settling time to 0.01% is 400 ns.

The device is stable with capacitive loads up to 10 nF, although the 6-MHz bandwidth decreases to 1.8 MHz at this high loading level. As such, the TLE2142 is useful for low-droop sample-and-holds and direct buffering of long cables, including 4-mA to 20-mA current loops.

The special design also exhibits an improved insensitivity to inherent integrated circuit component mismatches as is evidenced by a 500- μV maximum offset voltage and 1.7- $\mu\text{V}/^\circ\text{C}$ typical drift. Minimum common-mode rejection ratio and supply-voltage rejection ratio are 85 dB and 90 dB, respectively.

Device performance is relatively independent of supply voltage over the $\pm 2\text{-V}$ to $\pm 22\text{-V}$ range. Inputs can operate between $V_{CC-} - 0.3 \text{ V}$ to $V_{CC+} - 1.8 \text{ V}$ without inducing phase reversal, although excessive input current may flow out of each input exceeding the lower common-mode input range. The all-npn output stage provides a nearly rail-to-rail output swing of $V_{CC-} + 0.1 \text{ V}$ to $V_{CC+} - 1 \text{ V}$ under light current-loading conditions. The device can sustain shorts to either supply, because output current is internally limited, but care must be taken to ensure that maximum package power dissipation is not exceeded.

The TLE2142 can also be used as a comparator. Differential inputs of $V_{CC\pm}$ can be maintained without damage to the device. Open-loop propagation delay with TTL supply levels is typically 200 ns. This gives a good indication as to output stage saturation recovery when the device is driven beyond the limits of recommended output swing.

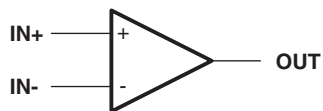
The TLE2142 device is available in industry-standard 8-pin small-outline (D) packages. The device is characterized for operation from -40°C to 125°C .



Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

Excilibur is a trademark of Texas Instruments.

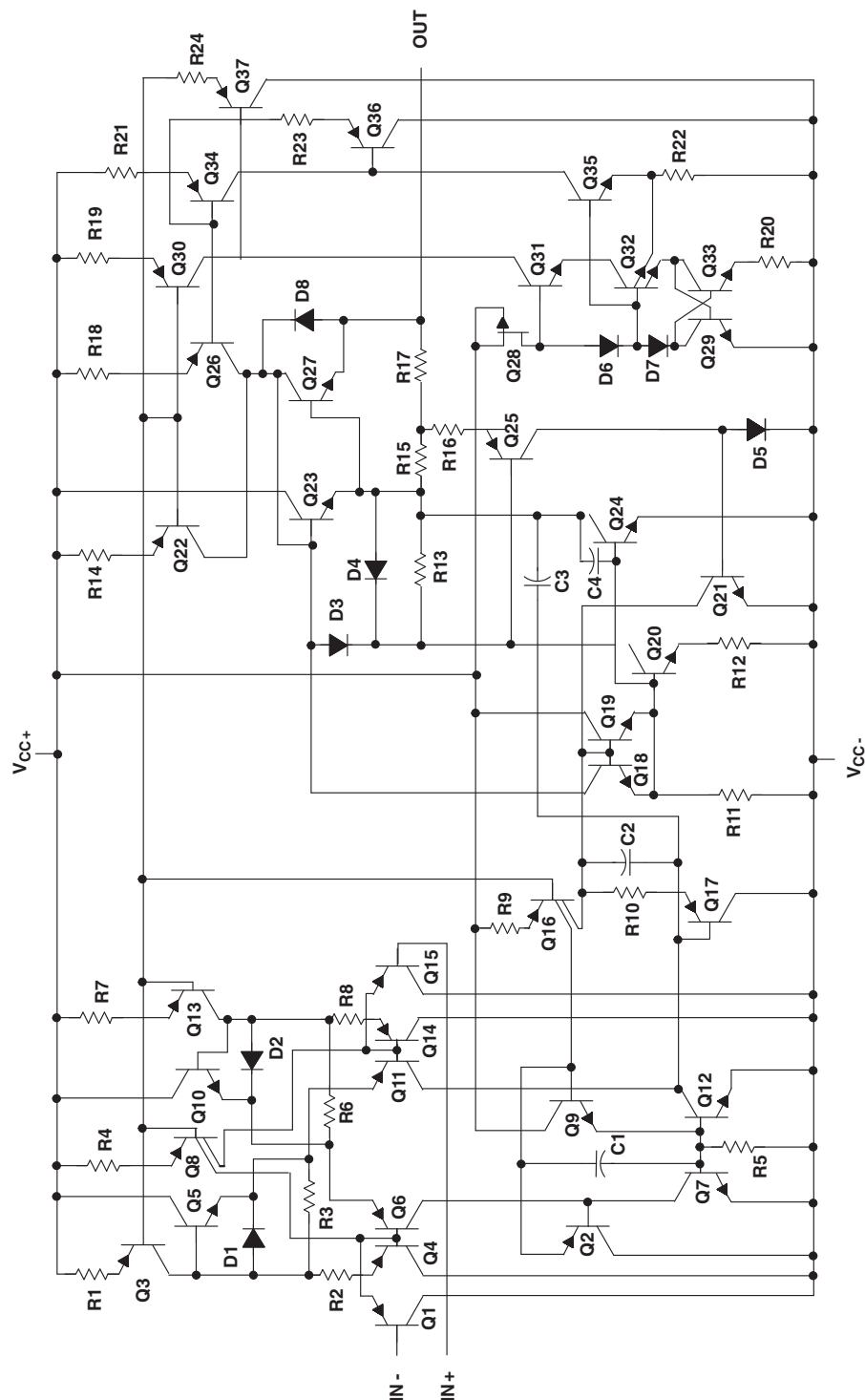
SYMBOL (EACH AMPLIFIER)

ORDERING INFORMATION⁽¹⁾

T _A	PACKAGE ⁽²⁾		ORDERABLE PART NUMBER	TOP-SIDE MARKING
–40°C to 125°C	SOIC – D	Reel of 2500	TLE2142QDRQ1	2142Q

- (1) For the most current package and ordering information, see the Package Option Addendum at the end of this document, or see the TI web site at www.ti.com.
- (2) Package drawings, thermal data, and symbolization are available at www.ti.com/packaging.

EQUIVALENT SCHEMATIC



DEVICE COMPONENT COUNT

COMPONENT	TLE2142
Transistors	65
Resistors	43
Diodes	14
Capacitors	8
Epi-FET	1

ABSOLUTE MAXIMUM RATINGS⁽¹⁾

over operating free-air temperature range (unless otherwise noted)

V_{CC+}	Supply voltage ⁽²⁾	22 V
V_{CC-}	Supply voltage	–22 V
V_{ID}	Differential input voltage ⁽³⁾	±44 V
V_I	Input voltage range (any input)	V_{CC+} to $(V_{CC-} - 0.3)$ V
I_I	Input current (each input)	±1 mA
I_O	Output current	±80 mA
	Total current into V_{CC+}	80 mA
	Total current out of V_{CC-}	80 mA
	Duration of short-circuit current at (or below) 25°C ⁽⁴⁾	Unlimited
θ_{JA}	Package thermal impedance ⁽⁵⁾⁽⁶⁾	97.1°C/W
T_A	Operating free-air temperature range	–40°C to 125°C
T_{stg}	Storage temperature range	–65°C to 150°C
	Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	260°C
ESD	Electrostatic discharge rating, Human-body model	500 V

- (1) Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.
- (2) All voltage values, except differential voltages, are with respect to the midpoint between V_{CC+} and V_{CC-} .
- (3) Differential voltages are at $IN+$ with respect to $IN-$. Excessive current flows, if input, are brought below $V_{CC-} - 0.3$ V.
- (4) The output may be shorted to either supply. Temperature and/or supply voltages must be limited to ensure that the maximum dissipation rating is not exceeded.
- (5) Maximum power dissipation is a function of $T_J(\max)$, θ_{JA} , and T_A . The maximum allowable power dissipation at any allowable ambient temperature is $P_D = (T_J(\max) - T_A)/\theta_{JA}$. Operating at the absolute maximum T_J of 150°C can affect reliability.
- (6) The package thermal impedance is calculated in accordance with JESD 51-7.

RECOMMENDED OPERATING CONDITIONS

			MIN	MAX	UNIT
V _{CC±}	Supply voltage		±2	±22	V
V _{IC}	Common-mode input voltage	V _{CC} = 5 V	0	2.7	V
		V _{CC±} = ±15 V	−15	12.7	
T _A	Operating free-air temperature		−40	125	°C

ELECTRICAL CHARACTERISTICS

$V_{CC} = 5\text{ V}$, at specified free-air temperature (unless otherwise noted)

PARAMETER	TEST CONDITIONS	$T_A^{(1)}$	MIN	TYP	MAX	UNIT
V_{IO} Input offset voltage	$V_O = 2.5\text{ V}$, $R_S = 50\ \Omega$, $V_{IC} = 2.5\text{ V}$	25°C		220	1900	μV
		Full range			2600	
α_{VIO} Temperature coefficient of input offset voltage	$V_O = 2.5\text{ V}$, $R_S = 50\ \Omega$, $V_{IC} = 2.5\text{ V}$	Full range		1.7		$\mu\text{V}/^\circ\text{C}$
I_{IO} Input offset current	$V_O = 2.5\text{ V}$, $R_S = 50\ \Omega$, $V_{IC} = 2.5\text{ V}$	25°C		8	100	nA
		Full range			200	
I_{IB} Input bias current	$V_O = 2.5\text{ V}$, $R_S = 50\ \Omega$, $V_{IC} = 2.5\text{ V}$	25°C		–0.8	–2	μA
		Full range			–2.3	
V_{ICR} Common-mode input voltage range	$R_S = 50\ \Omega$	25°C	0 to 3	–0.3 to 3.2		V
		Full range	0 to 2.7	–0.3 to 2.9		
V_{OH} High-level output voltage	$I_{OH} = -150\ \mu\text{A}$	25°C	3.9	4.1		V
	$I_{OH} = -1.5\text{ mA}$		3.8	4		
	$I_{OH} = -15\text{ mA}$		3.4	3.7		
	$I_{OH} = -100\ \mu\text{A}$	Full range	3.75			
	$I_{OH} = -1\text{ mA}$		3.65			
	$I_{OH} = -10\text{ mA}$		3.45			
V_{OL} Low-level output voltage	$I_{OL} = 150\ \mu\text{A}$	25°C		75	125	mV
	$I_{OL} = 1.5\text{ mA}$			150	225	
	$I_{OL} = 15\text{ mA}$			1.2	1.4	
	$I_{OL} = 100\ \mu\text{A}$	Full range			200	mV
	$I_{OL} = 1\text{ mA}$				250	
	$I_{OL} = 10\text{ mA}$				1.25	
A_{VD} Large-signal differential voltage amplification	$V_{IC} = \pm 2.5\text{ V}$, $R_L = 2\text{ k}\Omega$, $V_O = 1\text{ V to } -1.5\text{ V}$	25°C	50	220		V/mV
		Full range	5			
r_i Input resistance		25°C		70		M Ω
c_i Input capacitance		25°C		2.5		pF
z_o Open-loop output impedance	$f = 1\text{ MHz}$	25°C		30		Ω
CMRR Common-mode rejection ratio	$V_{IC} = V_{ICR(\text{min})}$, $R_S = 50\ \Omega$	25°C	85	118		dB
		Full range	80			
k_{SVR} Supply-voltage rejection ratio ($\Delta V_{CC\pm}/\Delta V_{IO}$)	$V_{CC\pm} = \pm 2.5\text{ V to } \pm 15\text{ V}$, $R_S = 50\ \Omega$	25°C	90	106		dB
		Full range	85			
I_{CC} Supply current	$V_O = 2.5\text{ V}$, No load, $V_{IC} = 2.5\text{ V}$	25°C		6.6	8.8	mA
		Full range			9.2	

(1) Full range is –40°C to 125°C.

OPERATING CHARACTERISTICS

$V_{CC} = 5\text{ V}$, $T_A = 25^\circ\text{C}$ (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
SR+	Positive slew rate	$A_{VD} = -1$, $R_L = 2\text{ k}\Omega^{(1)}$, $C_L = 500\text{ pF}$		45		V/ μs
SR–	Negative slew rate	$A_{VD} = -1$, $R_L = 2\text{ k}\Omega^{(1)}$, $C_L = 500\text{ pF}$		42		V/ μs
t_s	Settling time	$A_{VD} = -1$, 2.5-V step	To 0.1%	0.16		μs
			To 0.01%	0.22		
V_n	Equivalent input noise voltage	$R_S = 20\ \Omega$	f = 10 Hz	15		nV/ $\sqrt{\text{Hz}}$
			f = 1 kHz	10.5		
$V_{n(PP)}$	Peak-to-peak equivalent input noise voltage	f = 0.1 Hz to 1 Hz		0.48		μV
		f = 0.1 Hz to 10 Hz		0.51		
I_n	Equivalent input noise current	f = 10 Hz		1.92		pA/ $\sqrt{\text{Hz}}$
		f = 1 kHz		0.5		
THD+N	Total harmonic distortion plus noise	$V_O = 1\text{ V to }3\text{ V}$, $R_L = 2\text{ k}\Omega^{(1)}$, $A_{VD} = 2$, f = 10 kHz		0.0052		%
B_1	Unity-gain bandwidth	$R_L = 2\text{ k}\Omega^{(1)}$, $C_L = 100\text{ pF}$		5.9		MHz
	Gain-bandwidth product	$R_L = 2\text{ k}\Omega^{(1)}$, $C_L = 100\text{ pF}$, f = 100 kHz		5.8		MHz
BOM	Maximum output-swing bandwidth	$V_{O(PP)} = 2\text{ V}$, $R_L = 2\text{ k}\Omega^{(1)}$, $A_{VD} = 1$, $C_L = 100\text{ pF}$		660		kHz
ϕ_m	Phase margin at unity gain	$R_L = 2\text{ k}\Omega^{(1)}$, $C_L = 100\text{ pF}$		57		°

(1) R_L terminated at 2.5 V.

ELECTRICAL CHARACTERISTICS

 $V_{CC} = \pm 15\text{ V}$, at specified free-air temperature (unless otherwise noted)

PARAMETER		TEST CONDITIONS	$T_A^{(1)}$	MIN	TYP	MAX	UNIT
V_{IO}	Input offset voltage	$V_{IC} = 0$, $R_S = 50\ \Omega$	25°C		290	1200	μV
			Full range			2000	
α_{VIO}	Temperature coefficient of input offset voltage	$V_{IC} = 0$, $R_S = 50\ \Omega$	Full range		1.7		$\mu\text{V}/^\circ\text{C}$
I_{IO}	Input offset current	$V_{IC} = 0$, $R_S = 50\ \Omega$	25°C		7	100	nA
			Full range			250	
I_{IB}	Input bias current	$V_{IC} = 0$, $R_S = 50\ \Omega$	25°C		–0.7	–1.5	μA
			Full range			–1.8	
V_{ICR}	Common-mode input voltage range	$R_S = 50\ \Omega$	25°C	–15 to 13	–15.3 to 13.2		V
			Full range	–15 to 12.7	–15.3 to 12.9		
V_{OM+}	Maximum positive peak output voltage swing	$I_O = -150\ \mu\text{A}$	25°C		13.8	14.1	V
		$I_O = -1.5\ \text{mA}$			13.7	14	
		$I_O = -15\ \text{mA}$			13.3	13.7	
		$I_O = -100\ \mu\text{A}$	Full range		13.7		
		$I_O = -1\ \text{mA}$			13.6		
		$I_O = -10\ \text{mA}$			13.3		
V_{OM-}	Maximum negative peak output voltage swing	$I_O = 150\ \mu\text{A}$	25°C		–14.7	–14.9	V
		$I_O = 1.5\ \text{mA}$			–14.5	–14.8	
		$I_O = 15\ \text{mA}$			–13.4	–13.8	
		$I_O = 100\ \mu\text{A}$	Full range		–14.6		
		$I_O = 1\ \text{mA}$			–14.5		
		$I_O = 10\ \text{mA}$			–13.4		
A_{VD}	Large-signal differential voltage amplification	$V_O = \pm 10\ \text{V}$, $R_L = 2\ \text{k}\Omega$	25°C	100	450		V/mV
			Full range	20			
r_i	Input resistance		25°C		65		M Ω
c_i	Input capacitance		25°C		2.5		pF
z_o	Open-loop output impedance	$f = 1\ \text{MHz}$	25°C		30		Ω
CMRR	Common-mode rejection ratio	$V_{IC} = V_{ICR(\text{min})}$, $R_S = 50\ \Omega$	25°C	85	108		dB
			Full range	80			
k_{SVR}	Supply-voltage rejection ratio ($\Delta V_{CC\pm}/\Delta V_{IO}$)	$V_{CC\pm} = \pm 2.5\ \text{V}$ to $\pm 15\ \text{V}$, $R_S = 50\ \Omega$	25°C	90	106		dB
			Full range	85			
I_{OS}	Short-circuit output current	$V_O = 0$	25°C	$V_{ID} = 1\ \text{V}$	–25	–50	mA
				$V_{ID} = -1\ \text{V}$	20	31	
I_{CC}	Supply current	$V_O = 0$, No load, $V_{IC} = 2.5\ \text{V}$	25°C		6.9	9	mA
			Full range			9.4	

(1) Full range is –40°C to 125°C.

OPERATING CHARACTERISTICS

$V_{CC} = \pm 15\text{ V}$, $T_A = 25^\circ\text{C}$ (unless otherwise noted)

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
SR+	Positive slew rate	$A_{VD} = -1$, $R_L = 2\text{ k}\Omega$, $C_L = 100\text{ pF}$	27	45		V/ μs
SR–	Negative slew rate	$A_{VD} = -1$, $R_L = 2\text{ k}\Omega$, $C_L = 100\text{ pF}$	27	42		V/ μs
t_s	Settling time	$A_{VD} = -1$, 10-V step	To 0.1%	0.34		μs
			To 0.01%	0.4		
V_n	Equivalent input noise voltage	$R_S = 20\ \Omega$	f = 10 Hz	15		nV/ $\sqrt{\text{Hz}}$
			f = 1 kHz	10.5		
$V_{n(PP)}$	Peak-to-peak equivalent input noise voltage	f = 0.1 Hz to 1 Hz		0.48		μV
		f = 0.1 Hz to 10 Hz		0.51		
I_n	Equivalent input noise current	f = 10 Hz		1.89		pA/ $\sqrt{\text{Hz}}$
		f = 1 kHz		0.47		
THD+N	Total harmonic distortion plus noise	$V_{O(PP)} = 20\text{ V}$, $R_L = 2\text{ k}\Omega$, $A_{VD} = 10$, f = 10 kHz		0.01		%
B_1	Unity-gain bandwidth	$R_L = 2\text{ k}\Omega$, $C_L = 100\text{ pF}$		6		MHz
	Gain-bandwidth product	$R_L = 2\text{ k}\Omega$, $C_L = 100\text{ pF}$, f = 100 kHz		5.9		MHz
BOM	Maximum output-swing bandwidth	$V_{O(PP)} = 20\text{ V}$, $A_{VD} = 1$, $R_L = 2\text{ k}\Omega$, $C_L = 100\text{ pF}$		668		kHz
ϕ_m	Phase margin at unity gain	$R_L = 2\text{ k}\Omega$, $C_L = 100\text{ pF}$		58		°

TYPICAL CHARACTERISTICS

Table of Graphs

V_{IO}	Input offset voltage	Distribution	Figure 1
I_{IO}	Input offset current	vs Free-air temperature	Figure 2
I_{IB}	Input bias current	vs Common-mode input voltage	Figure 3
		vs Free-air temperature	Figure 4
V_{OM+}	Maximum positive peak output voltage	vs Supply voltage	Figure 5
		vs Free-air temperature	Figure 6
		vs Output current	Figure 7
		vs Settling time	Figure 9
V_{OM-}	Maximum negative peak output voltage	vs Supply voltage	Figure 5
		vs Free-air temperature	Figure 6
		vs Output current	Figure 8
		vs Settling time	Figure 9
$V_{O(PP)}$	Maximum peak-to-peak output voltage	vs Frequency	Figure 10
V_{OH}	High-level output voltage	vs Output current	Figure 11
V_{OL}	Low-level output voltage	vs Output current	Figure 12
	Phase shift	vs Frequency	Figure 13
A_{VD}	Large-signal differential voltage amplification	vs Frequency	Figure 13
		vs Free-air temperature	Figure 14
z_o	Closed-loop output impedance	vs Frequency	Figure 15
I_{OS}	Short-circuit output current	vs Free-air temperature	Figure 16
CMRR	Common-mode rejection ratio	vs Frequency	Figure 17
		vs Free-air temperature	Figure 18
k_{SVR}	Supply-voltage rejection ratio	vs Frequency	Figure 19
		vs Free-air temperature	Figure 20
I_{CC}	Supply current	vs Supply voltage	Figure 21
		vs Free-air temperature	Figure 22
V_n	Equivalent input noise voltage	vs Frequency	Figure 23
V_n	Input noise voltage	Over a 10-second period	Figure 24
I_n	Noise current	vs Frequency	Figure 25
THD+N	Total harmonic distortion plus noise	vs Frequency	Figure 26
SR	Slew rate	vs Free-air temperature	Figure 27
		vs Load capacitance	Figure 28
	Pulse response	Noninverting large signal	Figure 29
		Inverting large signal	Figure 30
		Small signal	Figure 31
B_1	Unity-gain bandwidth	vs Load capacitance	Figure 32
	Gain margin	vs Load capacitance	Figure 33
ϕ_m	Phase margin	vs Load capacitance	Figure 34

**TLE2142
DISTRIBUTION OF
INPUT OFFSET VOLTAGE**

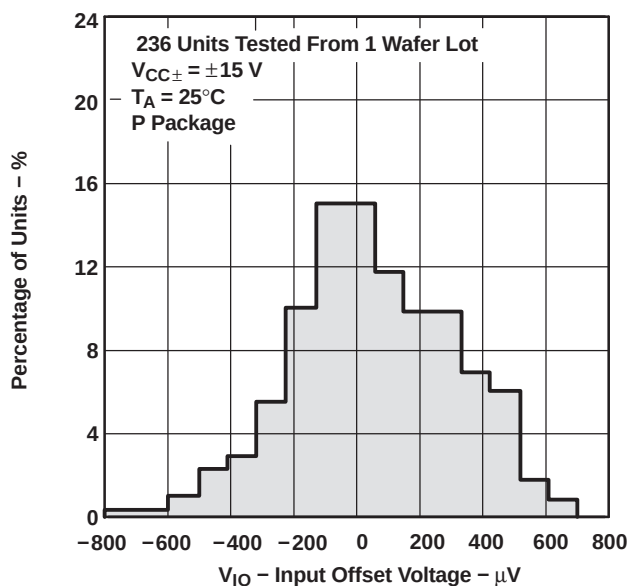


Figure 1.

**INPUT OFFSET CURRENT
VS
FREE-AIR TEMPERATURE**

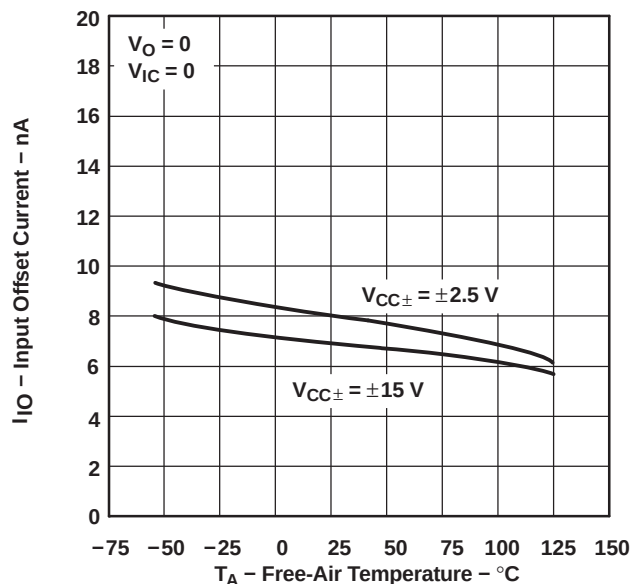


Figure 2.

**INPUT BIAS CURRENT
VS
COMMON-MODE INPUT VOLTAGE**

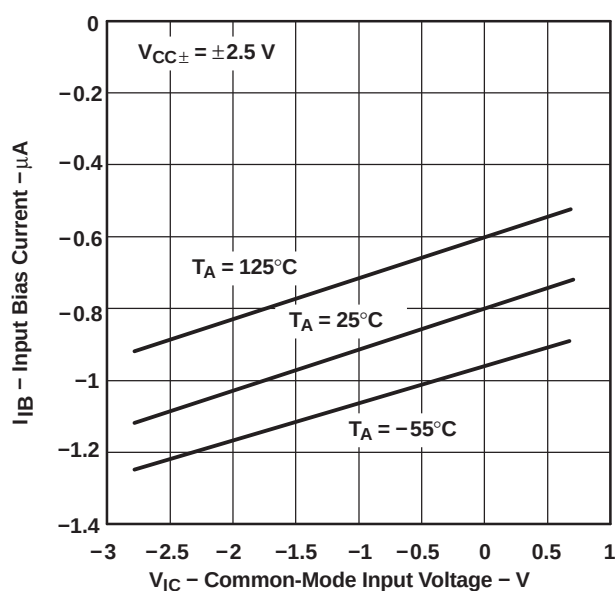


Figure 3.

**INPUT BIAS CURRENT
VS
FREE-AIR TEMPERATURE**

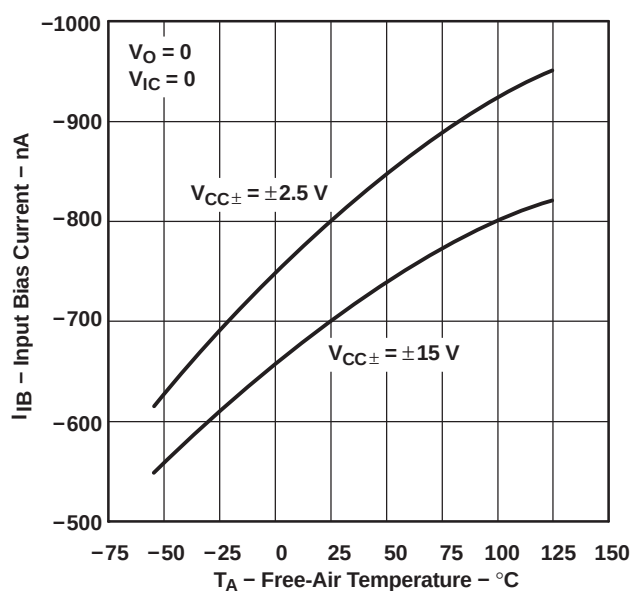


Figure 4.

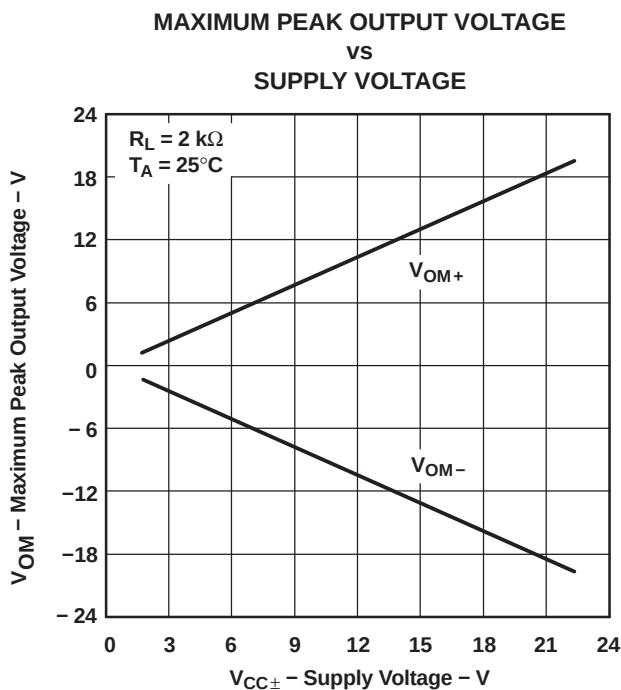


Figure 5.

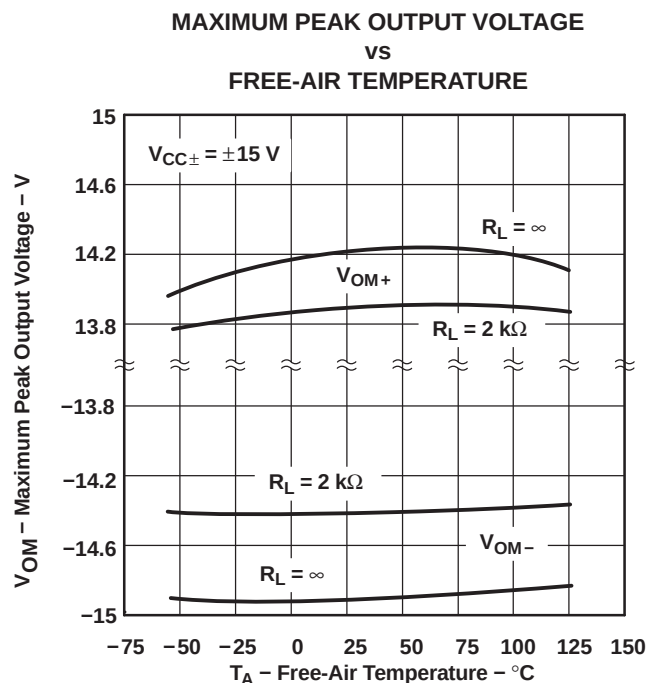


Figure 6.

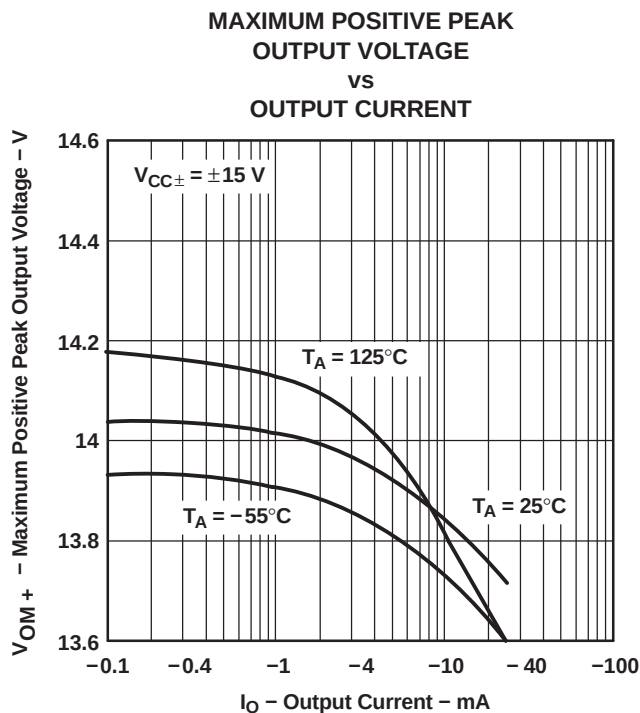


Figure 7.

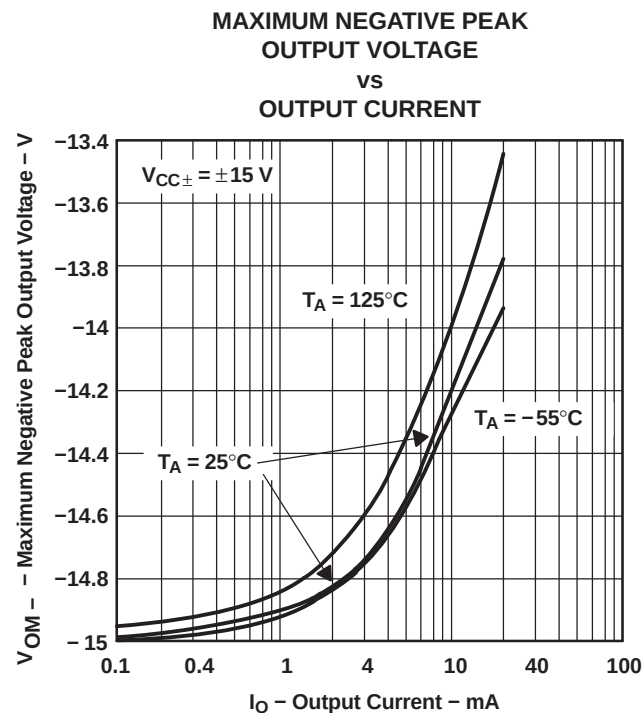


Figure 8.

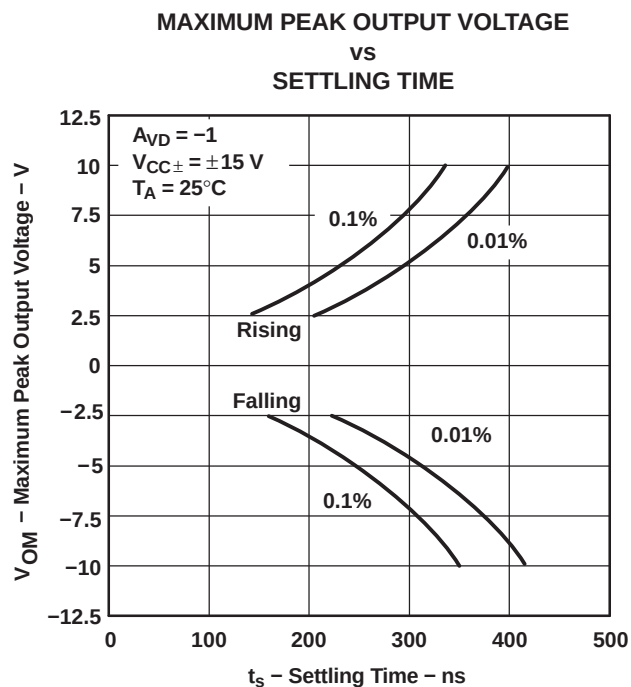


Figure 9.

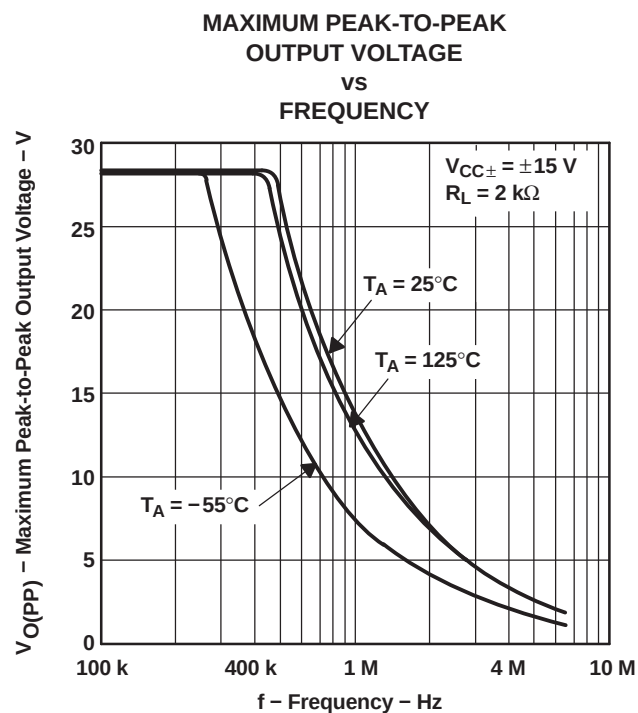


Figure 10.

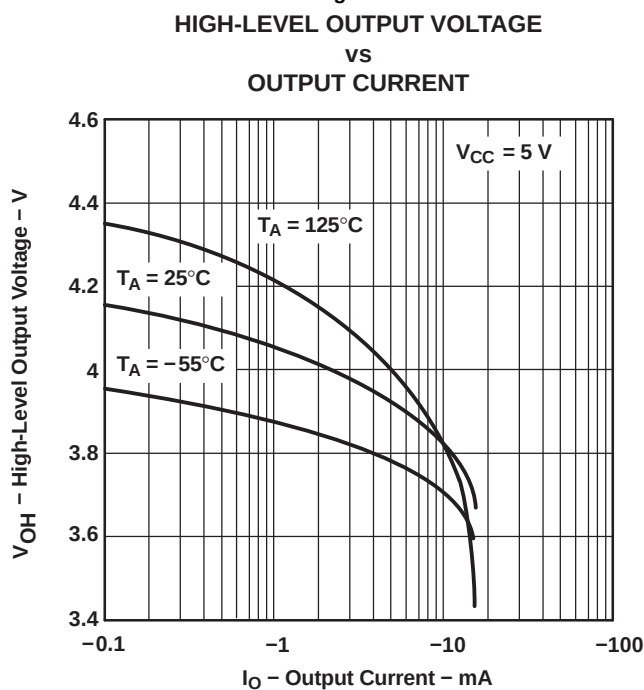


Figure 11.

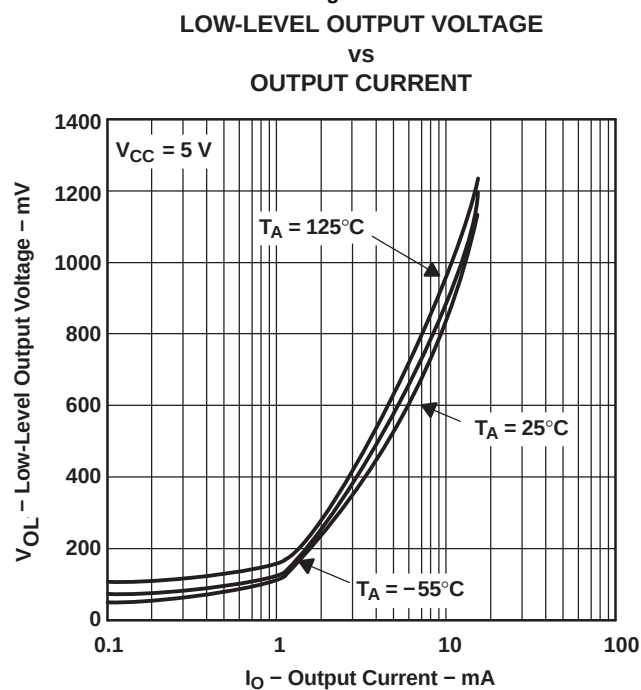


Figure 12.

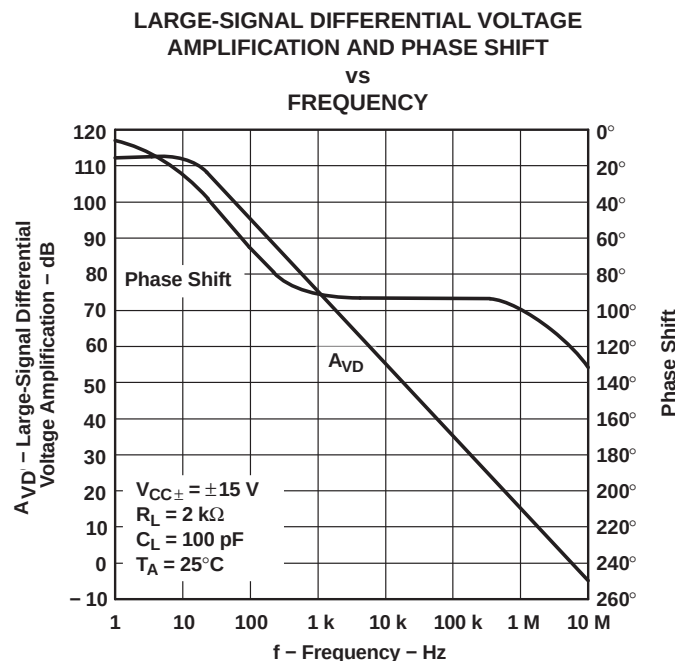


Figure 13.

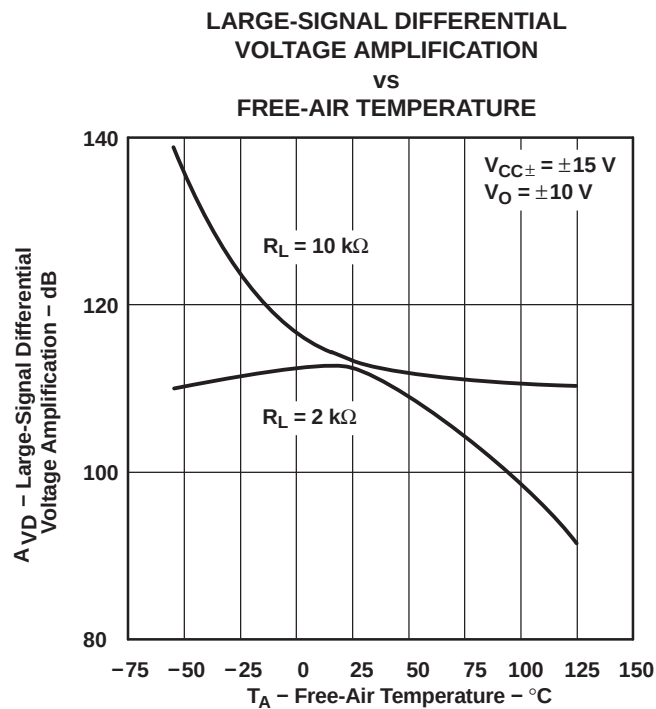


Figure 14.

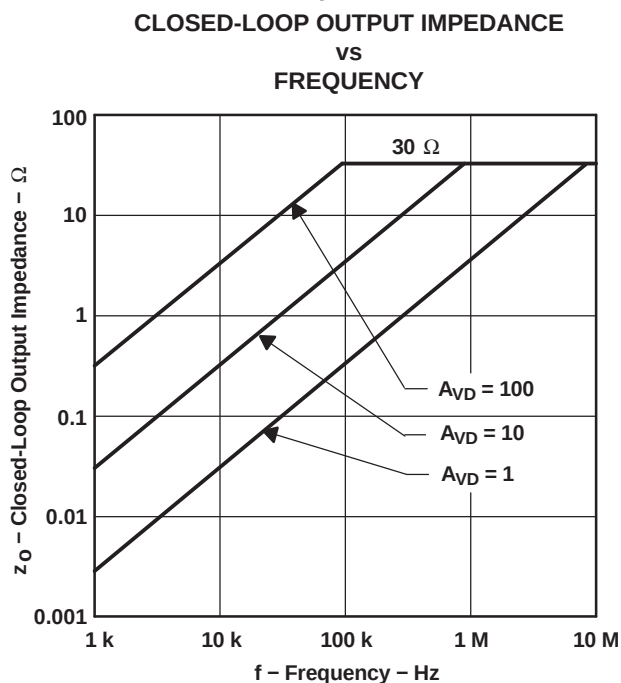


Figure 15.

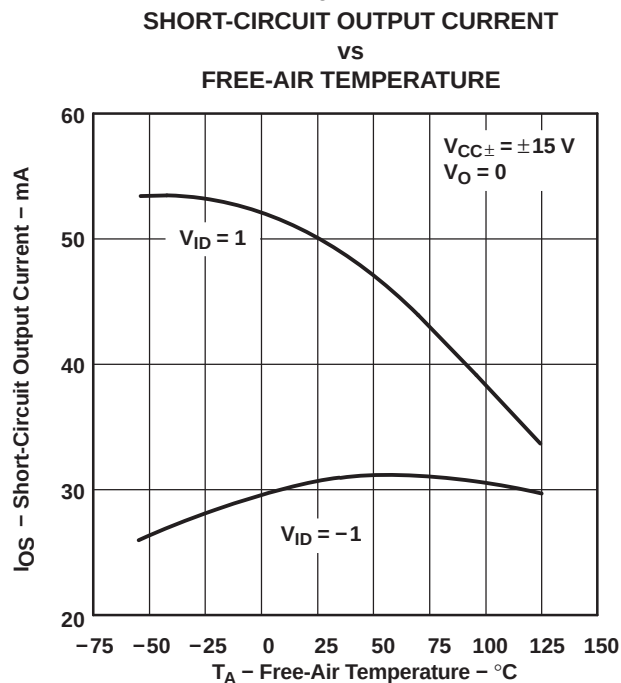


Figure 16.

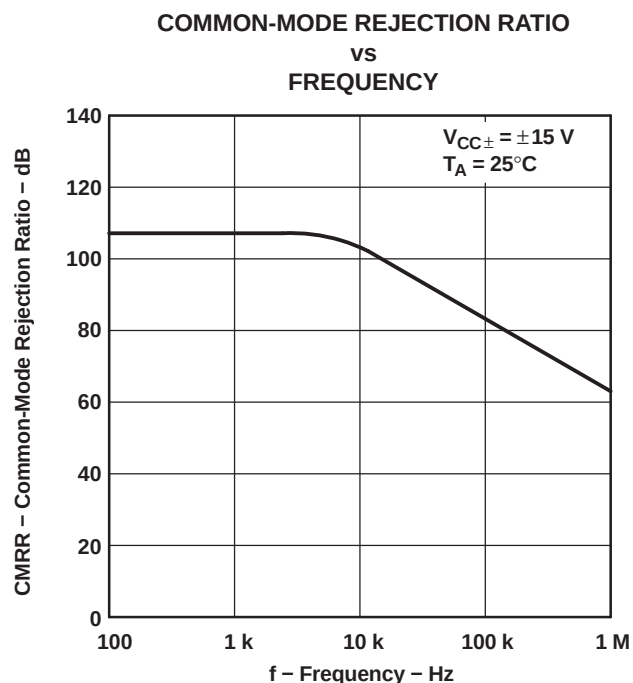


Figure 17.

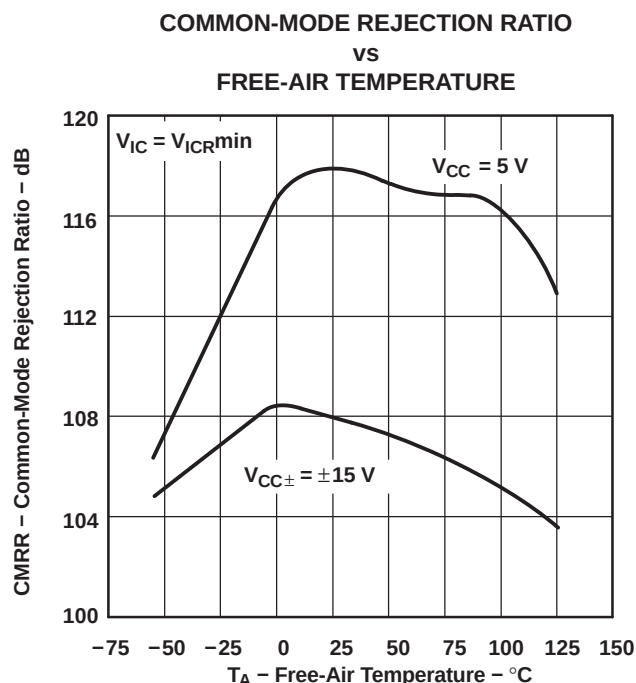


Figure 18.

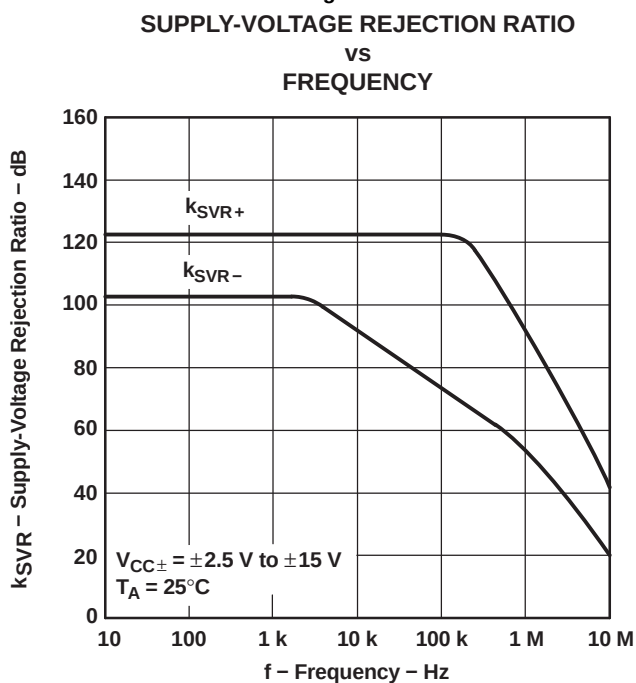


Figure 19.

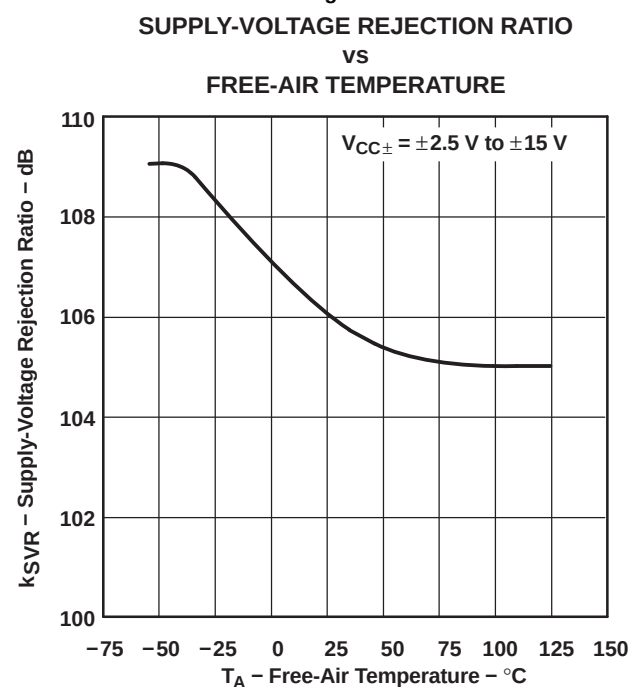


Figure 20.

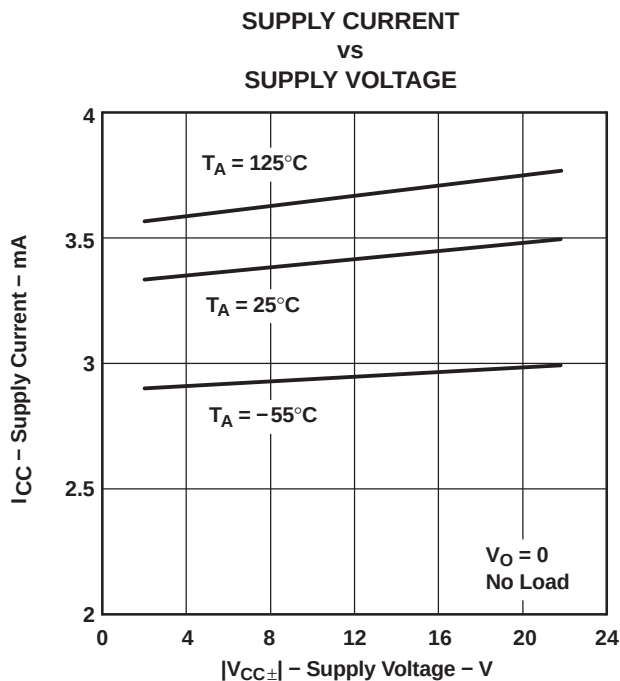


Figure 21.

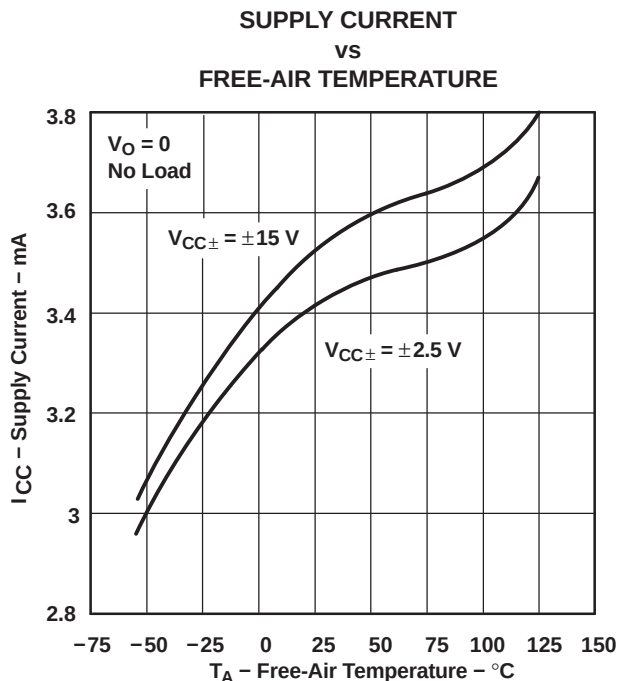


Figure 22.

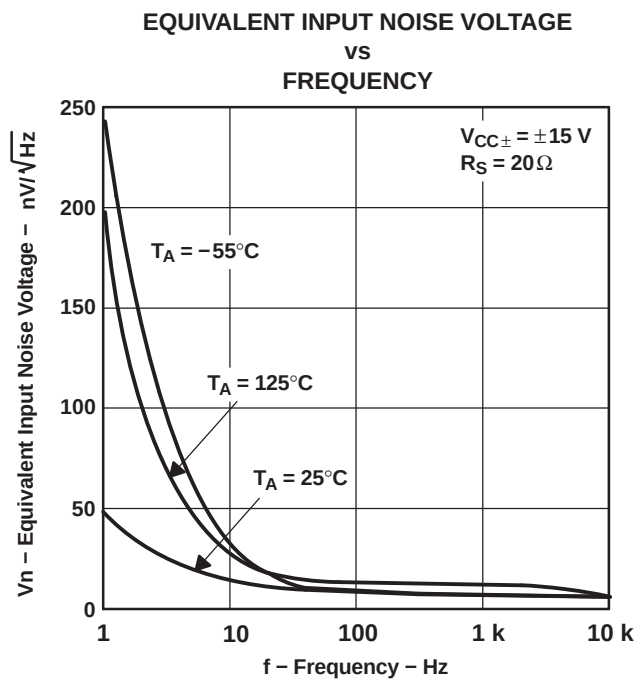


Figure 23.

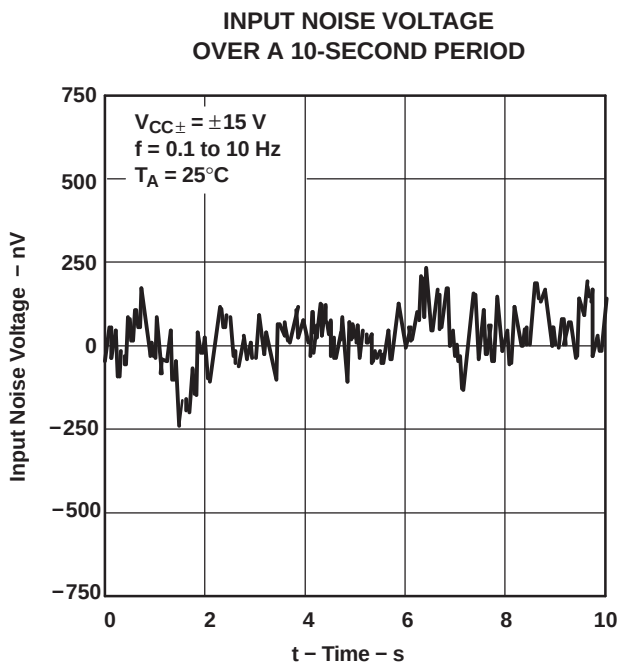


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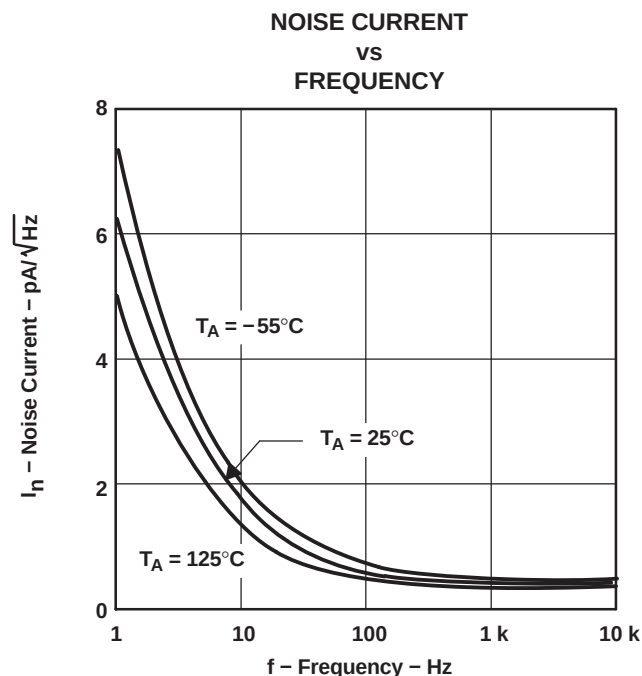


Figure 25.

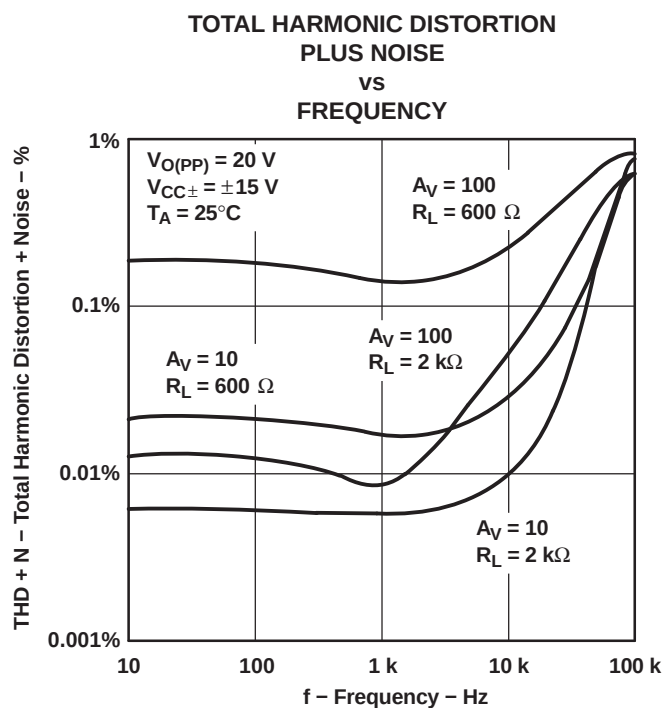


Figure 26.

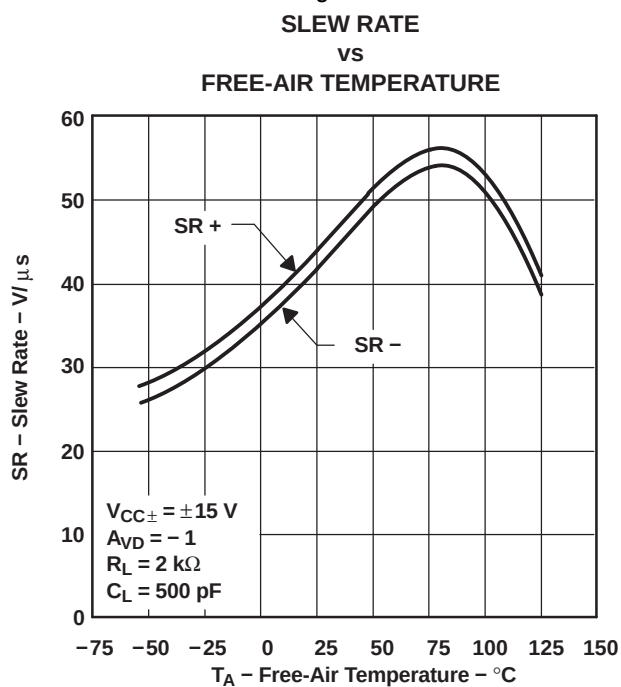


Figure 27.

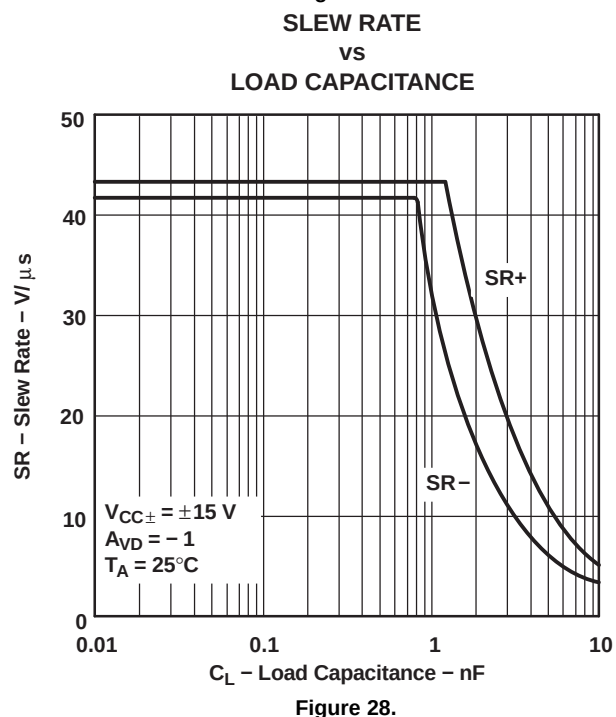
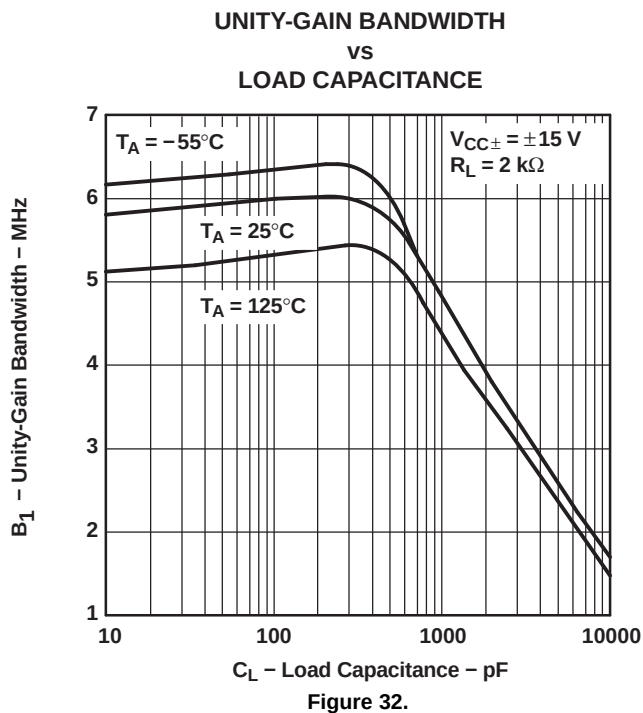
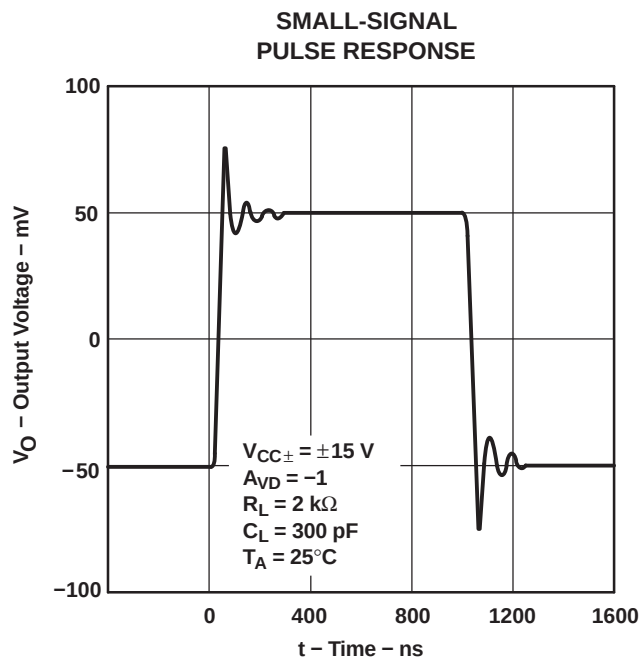
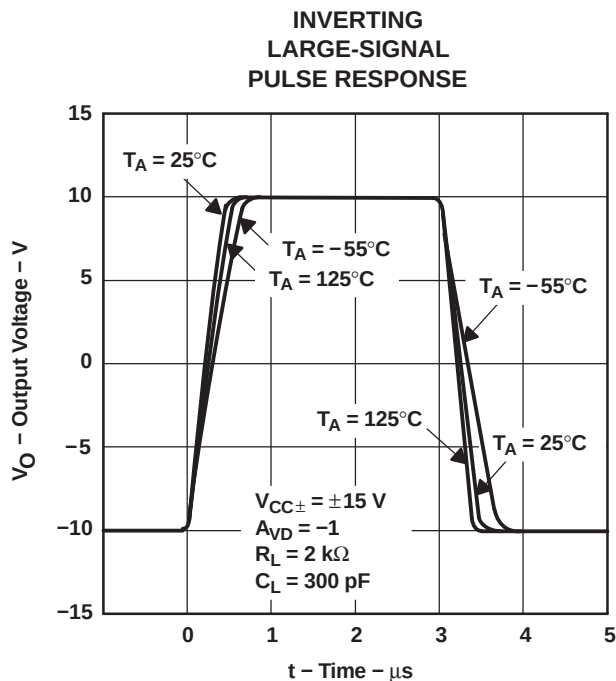
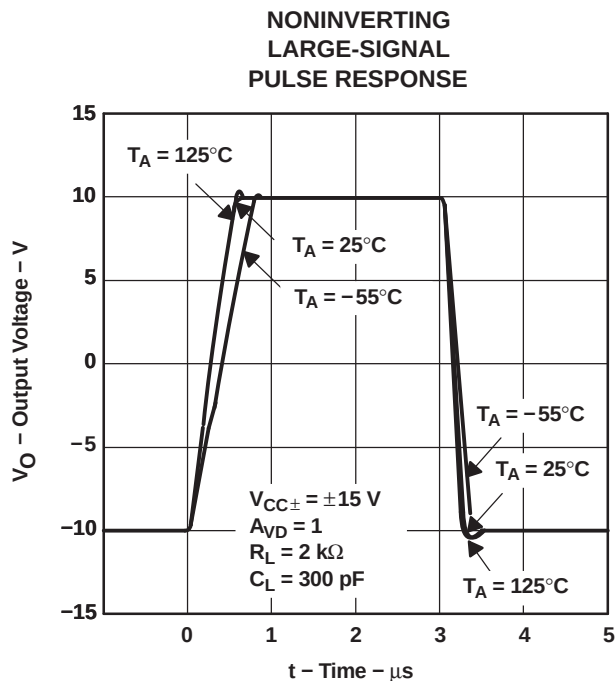
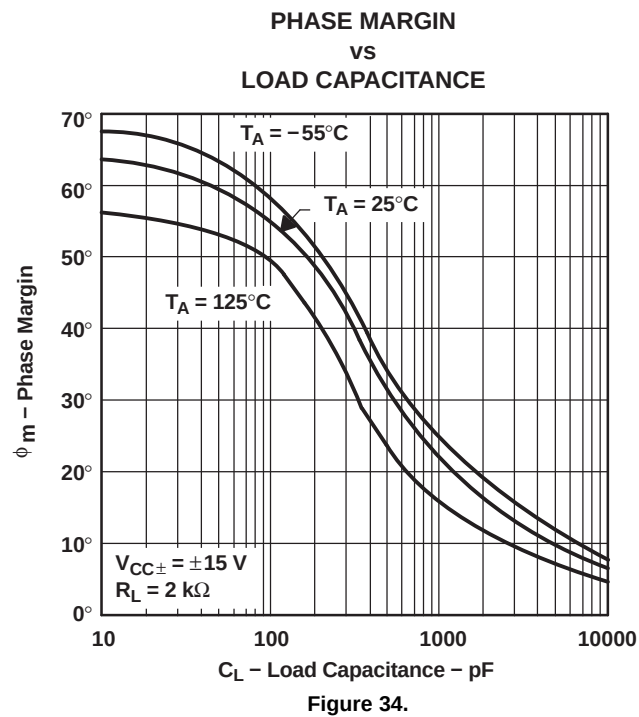
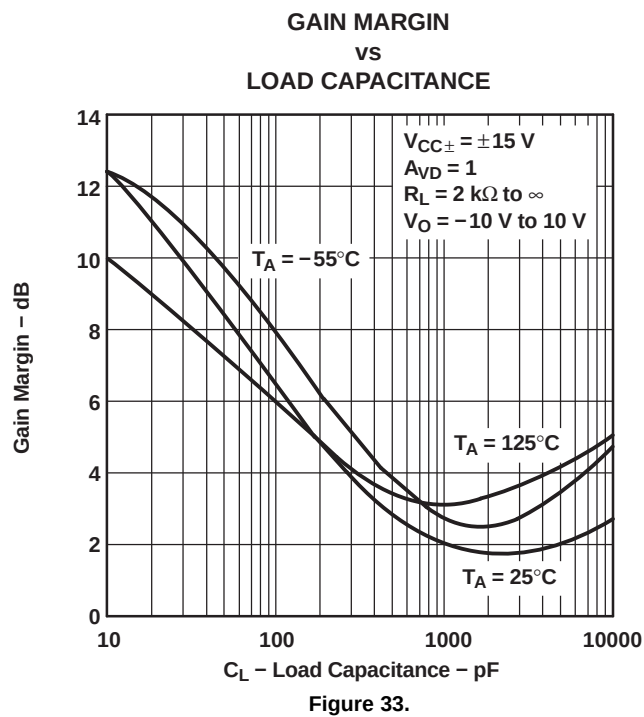


Figure 28.





PACKAGING INFORMATION

Orderable part number	Status (1)	Material type (2)	Package Pins	Package qty Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
TLE2142QDRQ1	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2142Q
TLE2142QDRQ1.A	Active	Production	SOIC (D) 8	2500 LARGE T&R	Yes	NIPDAU	Level-1-260C-UNLIM	-40 to 125	2142Q

⁽¹⁾ **Status:** For more details on status, see our [product life cycle](#).

⁽²⁾ **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

⁽³⁾ **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

⁽⁴⁾ **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

⁽⁵⁾ **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

⁽⁶⁾ **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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OTHER QUALIFIED VERSIONS OF TLE2142-Q1 :

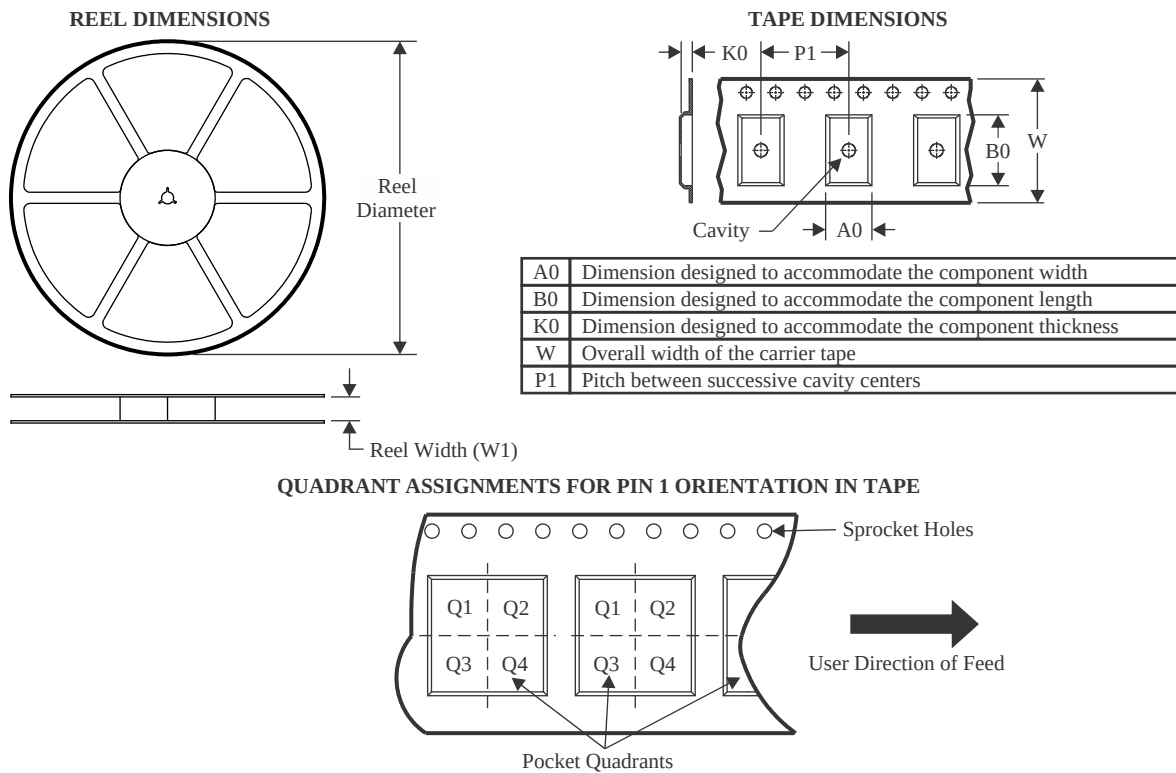
- Catalog : [TLE2142](#)

- Military : [TLE2142M](#)

NOTE: Qualified Version Definitions:

- Catalog - TI's standard catalog product
- Military - QML certified for Military and Defense Applications

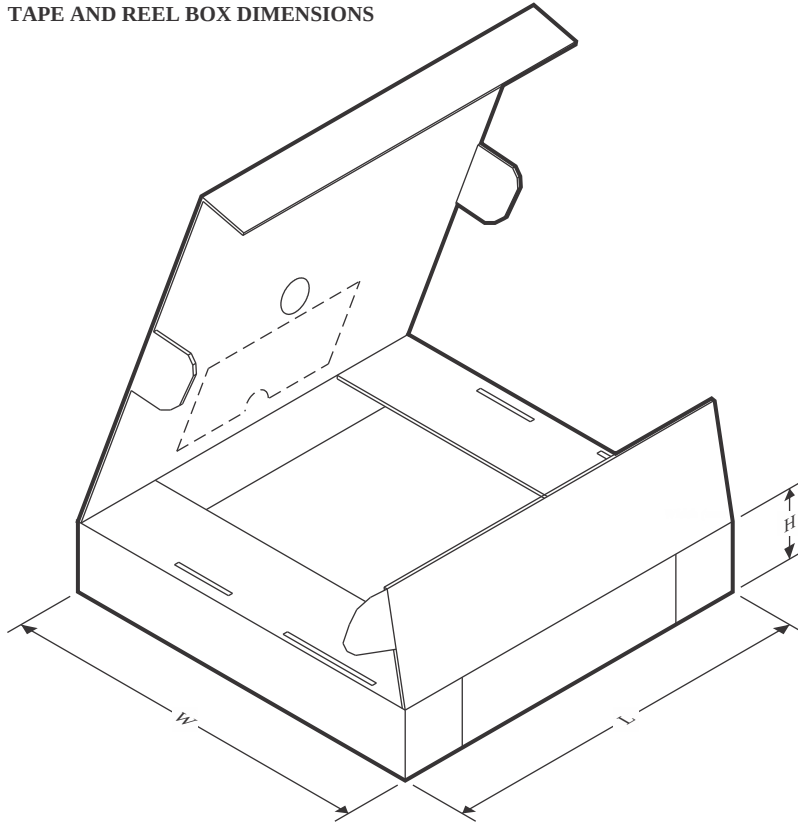
TAPE AND REEL INFORMATION



*All dimensions are nominal

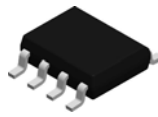
Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TLE2142QDRQ1	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1

TAPE AND REEL BOX DIMENSIONS



*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TLE2142QDRQ1	SOIC	D	8	2500	353.0	353.0	32.0

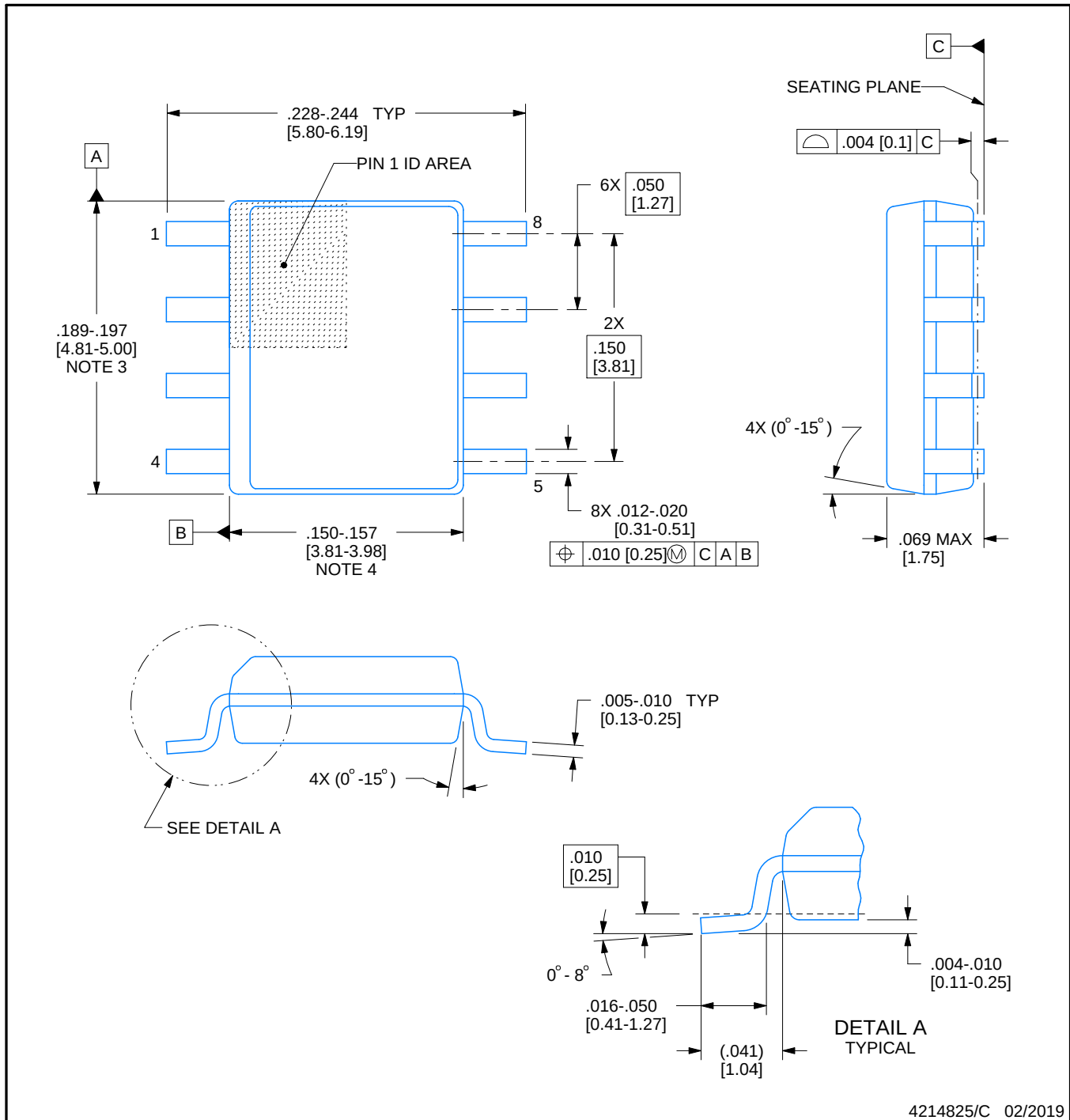


D0008A

PACKAGE OUTLINE

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



4214825/C 02/2019

NOTES:

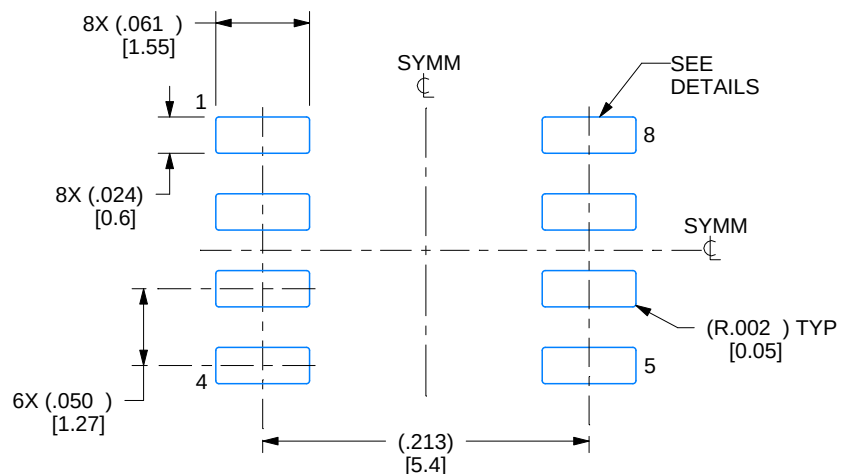
1. Linear dimensions are in inches [millimeters]. Dimensions in parenthesis are for reference only. Controlling dimensions are in inches. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed .006 [0.15] per side.
4. This dimension does not include interlead flash.
5. Reference JEDEC registration MS-012, variation AA.

EXAMPLE BOARD LAYOUT

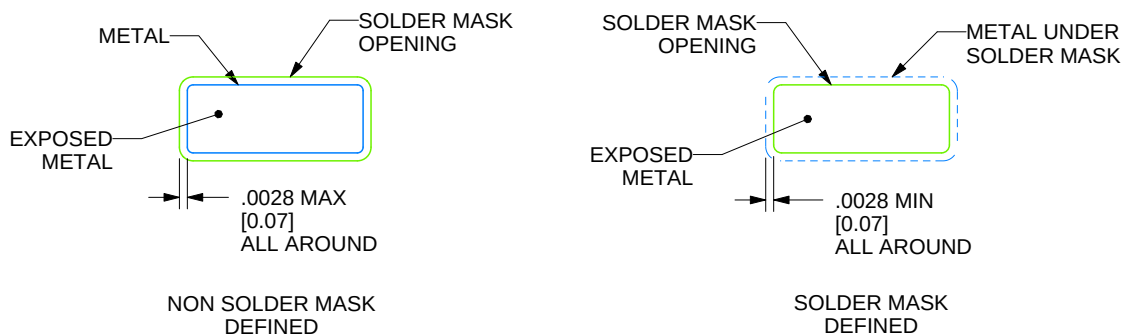
D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



LAND PATTERN EXAMPLE
EXPOSED METAL SHOWN
SCALE:8X



SOLDER MASK DETAILS

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NOTES: (continued)

6. Publication IPC-7351 may have alternate designs.

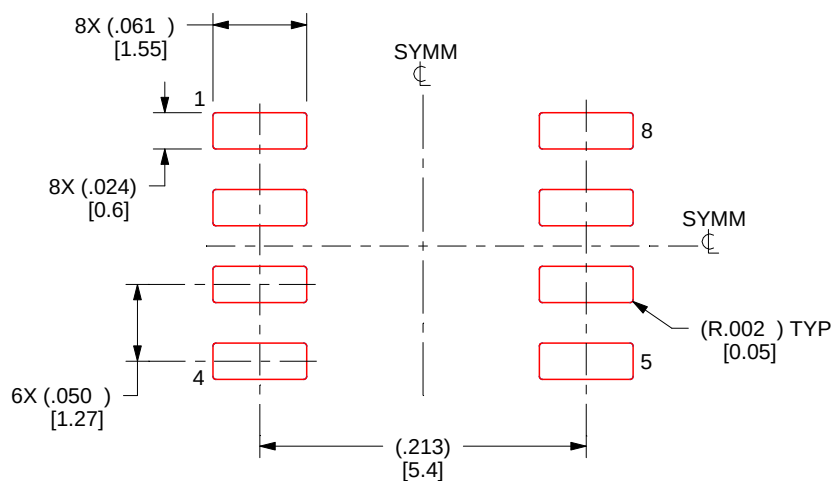
7. Solder mask tolerances between and around signal pads can vary based on board fabrication site.

EXAMPLE STENCIL DESIGN

D0008A

SOIC - 1.75 mm max height

SMALL OUTLINE INTEGRATED CIRCUIT



SOLDER PASTE EXAMPLE
BASED ON .005 INCH [0.125 MM] THICK STENCIL
SCALE:8X

4214825/C 02/2019

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

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